<u>TOSHIBA</u>

查询"2SA1298_07"供**应**窗HIBA Transistor Silicon PNP Epitaxial (PCT process)

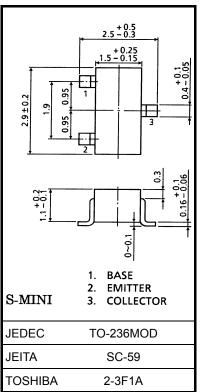
2SA1298

Low Frequency Power Amplifier Application Power Switching Applications

- High DC current gain: $h_{FE} = 100 \sim 320$
- Low saturation voltage: $V_{CE (sat)} = -0.4 V (max)$ (I_C = -500 mA, I_B = -20 mA)
- Suitable for driver stage of small motor
- Complementary to 2SC3265
- Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-30	V
Collector-emitter voltage	V _{CEO}	-25	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-800	mA
Base current	Ι _Β	-160	mA
Collector power dissipation	P _C	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C



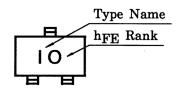
Weight: 0.012 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Unit: mm

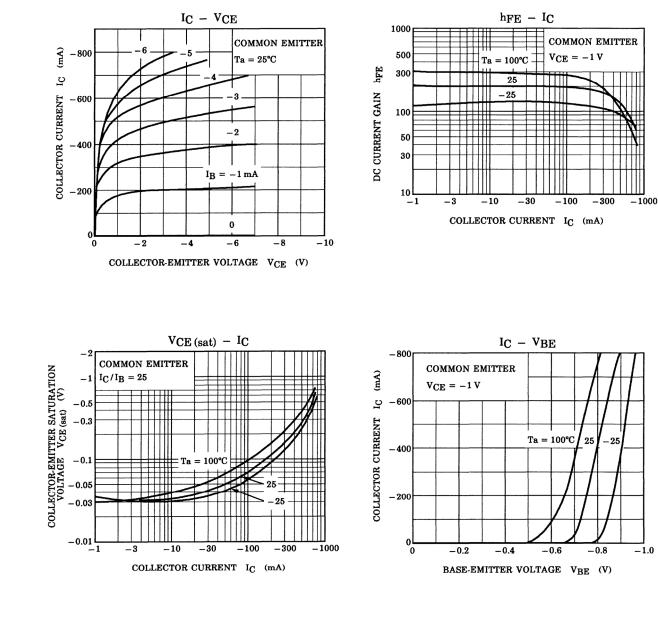
Etectrical Characteristics (Ta = 25°C)

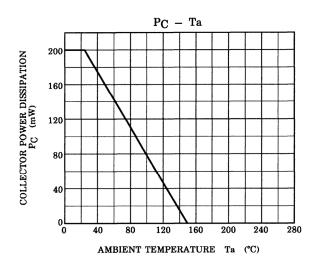
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -30 \text{ V}, \text{ I}_{E} = 0$			-0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -50 \text{ V}, \text{ I}_{C} = 0$	_		-0.1	μA
Collector-emitter breakdown voltage	V (BR) CEO	$I_{C} = -10 \text{ mA}, I_{B} = 0$	-25	_	—	V
Emitter-base breakdown voltage	V _{(BR) EBO}	$I_E = -0.1 \text{ mA}, I_C = 0$	-5	_	—	V
DC current gain	h _{FE (1)} (Note)	$V_{CE} = -1 \text{ V}, \text{ I}_{C} = -100 \text{ mA}$	100	_	320	
	h _{FE (2)}	$V_{CE} = -1 \text{ V}, \text{ I}_{C} = -800 \text{ mA}$	40	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = -500 \text{ mA}, I_{B} = -20 \text{ mA}$	_		-0.4	V
Base-emitter voltage	V _{BE}	$V_{CE} = -1 V, I_C = -10 mA$	-0.5		-0.8	V
Transition frequency	f _T	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -10 \text{ mA}$		120		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 V$, $I_E = 0$, $f = 1 MHz$	_	13	_	pF

Note: h_{FE (1)} classification O: 100~200, Y: 160~320

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20070701-EN GENERAL

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